



### 100V P-Channel Enhancement Mode MOSFET

Voltage

-100 V

Current

-10 A

#### **Features**

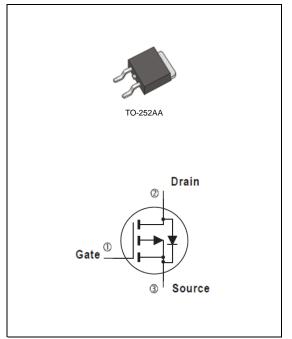
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-5A<210mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ , $I_{D}@-3A<230m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.. (Halogen Free)



• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-100	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	-10	А	
	T <sub>C</sub> =100°C		-6		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-40		
Power Dissipation	T <sub>C</sub> =25°C	Po	54	W	
	T <sub>C</sub> =100°C		22		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-2.0	Α	
	T <sub>A</sub> =70°C		-1.6	Α	
Power Dissipation	T <sub>A</sub> =25°C	-	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Po	1.3		
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2.3	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-100	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1.0	-1.9	-3.0	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-5A	-	170	210	mΩ	
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-3A	-	190	230		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-80V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	20	-	nC	
Gate-Source Charge	$Q_gs$		-	3.5	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-10V	-	4.6	-		
Input Capacitance	Ciss	05)/ )/ 0)/	-	1419	-	pF	
Output Capacitance	Coss	$V_{DS}$ =-25V, $V_{GS}$ =0V, $I_{S}$ =1.0MHZ	-	89	-		
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	45	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ F0\/\ID FA	-	18	-		
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =-50V,ID=-5A,	-	8	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =25 $\Omega$	-	100	-		
Turn-Off Fall Time	t <sub>f</sub>		-	30	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	-10	А	
Diode Forward Current	I <sub>S</sub>						
Reverse Recovery Time	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.74	-1.2	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

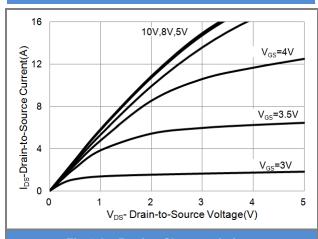
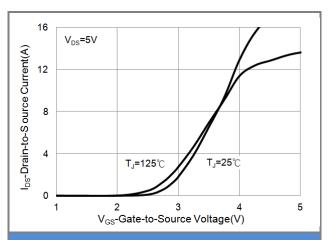


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

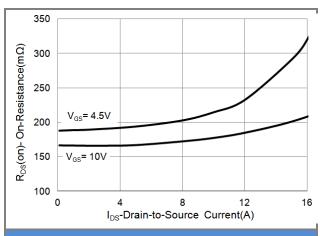


Fig.3 On-Resistance vs. Drain Current

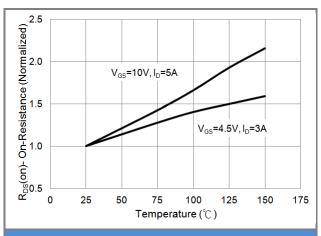


Fig.4 On-Resistance vs. Junction temperature

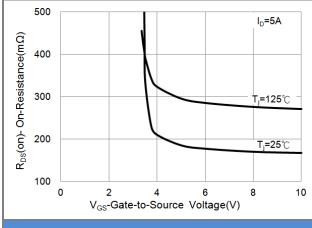
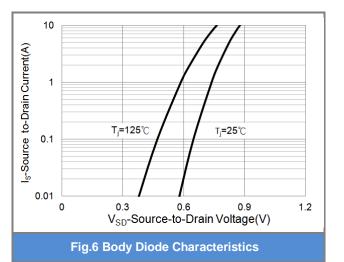


Fig.5 On-Resistance Variation with VGS.







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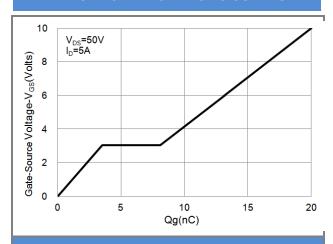


Fig.7 Gate-Charge Characteristics

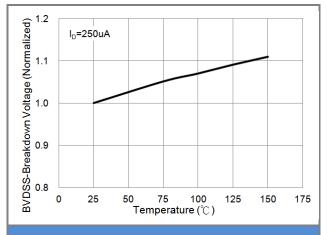


Fig.8 Breakdown Voltage Variation vs. Temperature

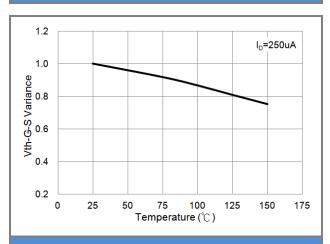


Fig.9 Threshold Voltage Variation with Temperature

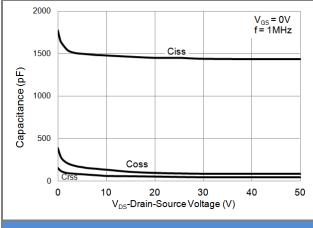
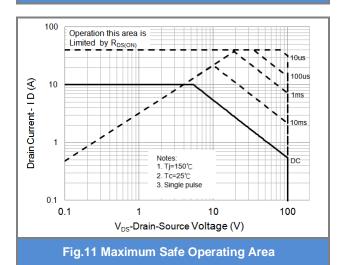


Fig.10 Capacitance vs. Drain-Source Voltage







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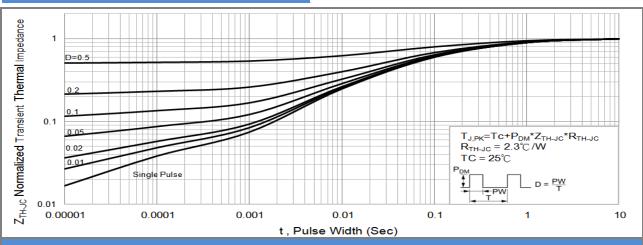
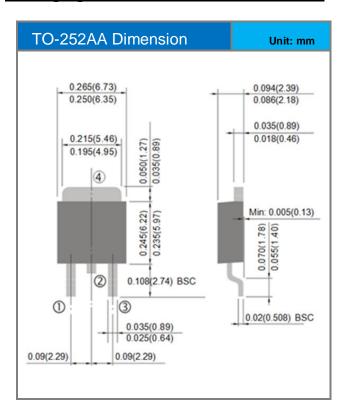


Fig.12 Normalized Thermal Transient Impedance





### **Packaging Information**



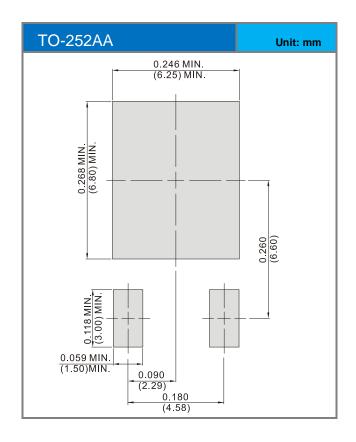




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	ng Type Marking	
PJD10P10A_L2_00001	TO-252AA	3,000pcs / 13" reel	D10P10A	Halogen free

### **MOUNTING PAD LAYOUT**







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